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Understanding [Embedded - FPGAs \(Field Programmable Gate Array\)](#)

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details

Product Status	Obsolete
Number of LABs/CLBs	295
Number of Logic Elements/Cells	-
Total RAM Bits	-
Number of I/O	34
Number of Gates	1200
Voltage - Supply	4.5V ~ 5.5V
Mounting Type	Surface Mount
Operating Temperature	0°C ~ 70°C (TA)
Package / Case	44-LCC (J-Lead)
Supplier Device Package	44-PLCC (16.59x16.59)
Purchase URL	https://www.e-xfl.com/product-detail/microsemi/a1010b-plg44c

The systems are available for 386/486/Pentium™ PC and for HP™ and Sun™ workstations and for running Viewlogic®,

Mentor Graphics®, Cadence™, OrCAD™, and Synopsys design environments.



Figure 1 • Partial View of an ACT 1 Device

ACT 1 Device Structure

A partial view of an ACT 1 device (Figure 1) depicts four logic modules and distributed horizontal and vertical interconnect tracks. PLICE antifuses, located at intersections of the horizontal and vertical tracks, connect logic module inputs and outputs. During programming, these antifuses are addressed and programmed to make the connections required by the circuit application.

The ACT 1 Logic Module

The ACT 1 logic module is an 8-input, one-output logic circuit chosen for the wide range of functions it implements and for its efficient use of interconnect routing resources (Figure 2).

The logic module can implement the four basic logic functions (NAND, AND, OR, and NOR) in gates of two, three, or four inputs. Each function may have many versions, with different combinations of active-low inputs. The logic module can also implement a variety of D-latches, exclusivity functions, AND-ORs, and OR-ANDs. No dedicated hardwired latches or flip-flops are required in the array, since latches and flip-flops may be constructed from logic modules wherever needed in the application.

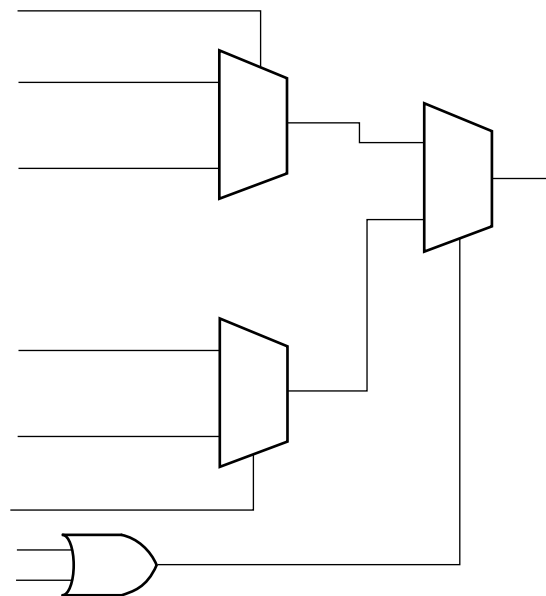


Figure 2 • ACT 1 Logic Module

I/O Buffers

Each I/O pin is available as an input, output, three-state, or bidirectional buffer. Input and output levels are compatible with standard TTL and CMOS specifications. Outputs sink or

source 10 mA at TTL levels. See Electrical Specifications for additional I/O buffer specifications.

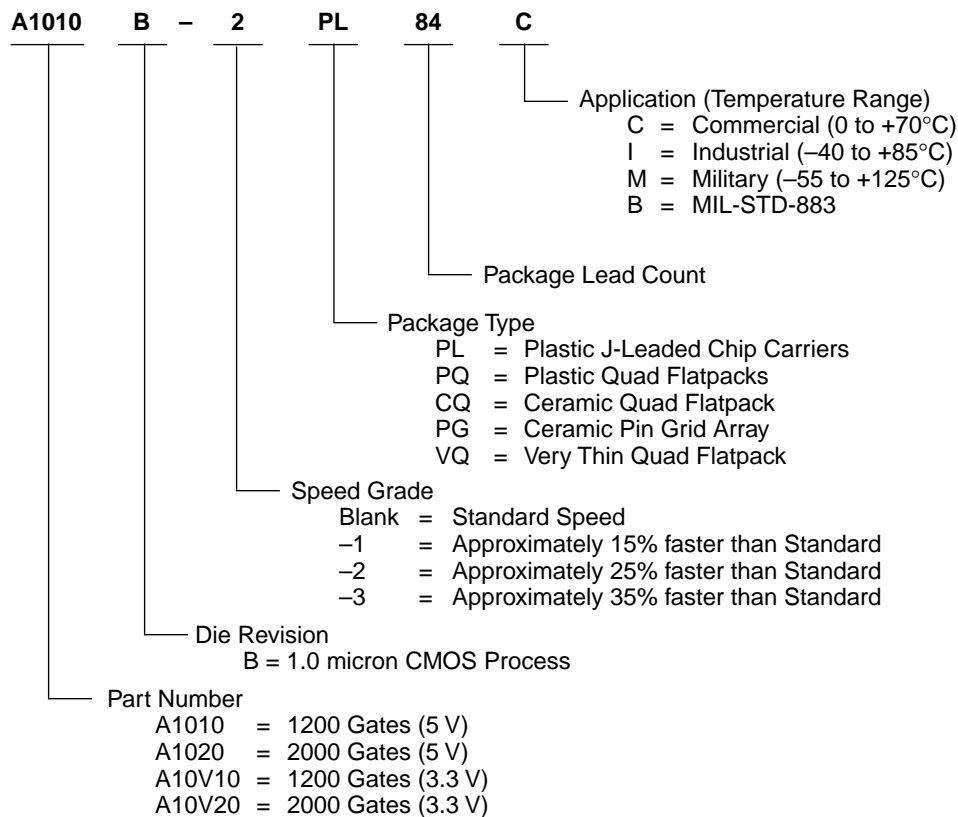
Device Organization

ACT 1 devices consist of a matrix of logic modules arranged in rows separated by wiring channels. This array is surrounded by a ring of peripheral circuits including I/O buffers, testability circuits, and diagnostic probe circuits providing real-time diagnostic capability. Between rows of logic modules are routing channels containing sets of segmented metal tracks with PLICE antifuses. Each channel has 22 signal tracks. Vertical routing is permitted via 13 vertical tracks per logic module column. The resulting network allows arbitrary and flexible interconnections between logic modules and I/O modules.

Probe Pin

ACT 1 devices have two independent diagnostic probe pins. These pins allow the user to observe any two internal signals by entering the appropriate net name in the diagnostic software. Signals may be viewed on a logic analyzer using Actel's Actionprobe® diagnostic tools. The probe pins can also be used as user-defined I/Os when debugging is finished.

Ordering Information



ACT 1 Array Performance

Temperature and Voltage Effects

Worst-case delays for ACT 1 arrays are calculated in the same manner as for masked array products. A typical delay parameter is multiplied by a derating factor to account for temperature, voltage, and processing effects. However, in an ACT 1 array, temperature and voltage effects are less dramatic than with masked devices. The electrical characteristics of module interconnections on ACT 1 devices remain constant over voltage and temperature fluctuations.

As a result, the total derating factor from typical to worst-case for a standard speed ACT 1 array is only 1.19 to 1, compared to 2 to 1 for a masked gate array.

Logic Module Size

Logic module size also affects performance. A mask programmed gate array cell with four transistors usually implements only one logic level. In the more complex logic module (similar to the complexity of a gate array macro) of an ACT 1 array, implementation of multiple logic levels within a single module is possible. This eliminates interlevel wiring and associated RC delays. The effect is termed "net compression."

Product Plan

	Speed Grade*				Application			
	Std	-1	-2	-3	C	I	M	B
A1010B Device								
44-pin Plastic Leaded Chip Carrier (PL)	✓	✓	✓	✓	✓	✓	—	—
68-pin Plastic Leaded Chip Carrier (PL)	✓	✓	✓	✓	✓	✓	—	—
100-pin Plastic Quad Flatpack (PQ)	✓	✓	✓	✓	✓	✓	—	—
80-pin Very Thin (1.0 mm) Quad Flatpack (VQ)	✓	✓	✓	✓	✓	—	—	—
84-pin Ceramic Pin Grid Array (PG)	✓	✓	—	—	✓	—	✓	✓
A1020B Device								
44-pin Plastic Leaded Chip Carrier (PL)	✓	✓	✓	✓	✓	✓	—	—
68-pin Plastic Leaded Chip Carrier (PL)	✓	✓	✓	✓	✓	✓	—	—
84-pin Plastic Leaded Chip Carrier (PL)	✓	✓	✓	✓	✓	✓	—	—
100-pin Plastic Quad Flatpack (PQ)	✓	✓	✓	✓	✓	✓	—	—
80-pin Very Thin (1.0 mm) Quad Flatpack (VQ)	✓	✓	✓	✓	✓	—	—	—
84-pin Ceramic Pin Grid Array (PG)	✓	✓	—	—	✓	—	✓	✓
84-pin Ceramic Quad Flatpack (CQ)	✓	✓	—	—	✓	—	✓	✓
A10V10B Device								
68-pin Plastic Leaded Chip Carrier (PL)	✓	—	—	—	✓	—	—	—
80-pin Very Thin (1.0 mm) Quad Flatpack (VQ)	✓	—	—	—	✓	—	—	—
A10V20B Device								
68-pin Plastic Leaded Chip Carrier (PL)	✓	—	—	—	✓	—	—	—
84-pin Plastic Leaded Chip Carrier (PL)	✓	—	—	—	✓	—	—	—
80-pin Very Thin (1.0 mm) Quad Flatpack (VQ)	✓	—	—	—	✓	—	—	—

Applications: C = Commercial Availability: ✓ = Available * Speed Grade: -1 = Approx. 15% faster than Standard
 I = Industrial P = Planned -2 = Approx. 25% faster than Standard
 M = Military — = Not Planned -3 = Approx. 35% faster than Standard
 B = MIL-STD-883

Device Resources

Device	Logic Modules	Gates	User I/Os				
			44-pin	68-pin	80-pin	84-pin	100-pin
A1010B, A10V10B	295	1200	34	57	57	57	57
A1020B, A10V20B	547	2000	34	57	69	69	69

Pin Description

CLK Clock (Input)

TTL Clock input for global clock distribution network. The Clock input is buffered prior to clocking the logic modules. This pin can also be used as an I/O.

DCLK Diagnostic Clock (Input)

TTL Clock input for diagnostic probe and device programming. DCLK is active when the MODE pin is HIGH. This pin functions as an I/O when the MODE pin is LOW.

GND Ground

Input LOW supply voltage.

I/O Input/Output (Input, Output)

I/O pin functions as an input, output, three-state, or bidirectional buffer. Input and output levels are compatible with standard TTL and CMOS specifications. Unused I/O pins are automatically driven LOW by the ALS software.

MODE Mode (Input)

The MODE pin controls the use of multifunction pins (DCLK, PRA, PRB, SDI). When the MODE pin is HIGH, the special functions are active. When the MODE pin is LOW, the pins function as I/O. To provide Actionprobe capability, the MODE pin should be terminated to GND through a 10K resistor so that the MODE pin can be pulled high when required.

NC No Connection

This pin is not connected to circuitry within the device.

PRA Probe A (Output)

The Probe A pin is used to output data from any user-defined design node within the device. This independent diagnostic pin is used in conjunction with the Probe B pin to allow real-time diagnostic output of any signal path within the device. The Probe A pin can be used as a user-defined I/O when debugging has been completed. The pin's probe capabilities can be permanently disabled to protect the programmed design's confidentiality. PRA is active when the MODE pin is HIGH. This pin functions as an I/O when the MODE pin is LOW.

PRB Probe B (Output)

The Probe B pin is used to output data from any user-defined design node within the device. This independent diagnostic pin is used in conjunction with the Probe A pin to allow real-time diagnostic output of any signal path within the device. The Probe B pin can be used as a user-defined I/O when debugging has been completed. The pin's probe capabilities can be permanently disabled to protect the programmed design's confidentiality. PRB is active when the MODE pin is HIGH. This pin functions as an I/O when the MODE pin is LOW.

SDI Serial Data Input (Input)

Serial data input for diagnostic probe and device programming. SDI is active when the MODE pin is HIGH. This pin functions as an I/O when the MODE pin is LOW.

V_{CC} Supply Voltage

Input HIGH supply voltage.

Absolute Maximum Ratings¹

Free air temperature range

Symbol	Parameter	Limits	Units
V _{CC}	DC Supply Voltage ²	−0.5 to +7.0	Volts
V _I	Input Voltage	−0.5 to V _{CC} +0.5	Volts
V _O	Output Voltage	−0.5 to V _{CC} +0.5	Volts
I _{IO}	I/O Sink/Source Current ³	±20	mA
T _{STG}	Storage Temperature	−65 to +150	°C

Notes:

- Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. Exposure to absolute maximum rated conditions for extended periods may affect device reliability. Device should not be operated outside the Recommended Operating Conditions.
- V_{PP} = V_{CC}, except during device programming.
- Device inputs are normally high impedance and draw extremely low current. However, when input voltage is greater than V_{CC} + 0.5 V or less than GND − 0.5 V, the internal protection diode will be forward biased and can draw excessive current.

Recommended Operating Conditions

Parameter	Commercial	Industrial	Military	Units
Temperature Range ¹	0 to +70	−40 to +85	−55 to +125	°C
Power Supply Tolerance	±5	±10	±10	%V _{CC}

Note:

- Ambient temperature (T_A) used for commercial and industrial; case temperature (T_C) used for military.

Electrical Specifications (5V)

Symbol	Parameter	Commercial		Industrial		Military		Units
		Min.	Max.	Min.	Max.	Min.	Max.	
V_{OH}^1	$(I_{OH} = -10 \text{ mA})^2$	2.4						V
	$(I_{OH} = -6 \text{ mA})$	3.84						V
	$(I_{OH} = -4 \text{ mA})$			3.7		3.7		V
V_{OL}^1	$(I_{OL} = 10 \text{ mA})^2$		0.5					V
	$(I_{OL} = 6 \text{ mA})$		0.33		0.40		0.40	V
V_{IL}		-0.3	0.8	-0.3	0.8	-0.3	0.8	V
V_{IH}		2.0	$V_{CC} + 0.3$	2.0	$V_{CC} + 0.3$	2.0	$V_{CC} + 0.3$	V
Input Transition Time t_R, t_F^2			500		500		500	ns
C_{IO} I/O Capacitance ^{2, 3}			10		10		10	pF
Standby Current, I_{CC}^4 (typical = 1 mA)			3		10		20	mA
Leakage Current ⁵		-10	10	-10	10	-10	10	μA

Notes:

1. Only one output tested at a time. $V_{CC} = \text{min.}$
2. Not tested, for information only.
3. Includes worst-case 84-pin PLCC package capacitance. $V_{OUT} = 0 \text{ V}, f = 1 \text{ MHz.}$
4. Typical standby current = 1 mA. All outputs unloaded. All inputs = V_{CC} or GND.
5. $V_O, V_{IN} = V_{CC}$ or GND.

Electrical Specifications (3.3V)

Parameter		Commercial		Units
		Min.	Max.	
V_{OH}^1	$(I_{OH} = -4 \text{ mA})$	2.15		V
	$(I_{OH} = -3.2 \text{ mA})$	2.4		V
V_{OL}^1	$(I_{OL} = 6 \text{ mA})$		0.4	V
V_{IL}		-0.3	0.8	V
V_{IH}		2.0	$V_{CC} + 0.3$	V
Input Transition Time t_R, t_F^2			500	ns
C_{IO} I/O Capacitance ^{2, 3}			10	pF
Standby Current, I_{CC}^4 (typical = 0.3 mA)			0.75	mA
Leakage Current ⁵		-10	10	μA

Notes:

1. Only one output tested at a time. $V_{CC} = \text{min.}$
2. Not tested, for information only.
3. Includes worst-case 84-pin PLCC package capacitance. $V_{OUT} = 0 \text{ V}, f = 1 \text{ MHz.}$
4. Typical standby current = 0.3 mA. All outputs unloaded. All inputs = V_{CC} or GND.
5. $V_O, V_{IN} = V_{CC}$ or GND

Package Thermal Characteristics

The device junction to case thermal characteristics is θ_{jc} , and the junction to ambient air characteristics is θ_{ja} . The thermal characteristics for θ_{ja} are shown with two different air flow rates. Maximum junction temperature is 150°C.

A sample calculation of the maximum power dissipation for an 84-pin plastic leaded chip carrier at commercial temperature is as follows:

$$\frac{\text{Max junction temp.}(\text{°C}) - \text{Max commercial temp.}(\text{°C})}{\theta_{ja}(\text{°C/W})} = \frac{150\text{°C} - 70\text{°C}}{37\text{°C/W}} = 2.2 \text{ W}$$

Package Type	Pin Count	θ_{jc}	θ_{ja} Still Air	θ_{ja} 300 ft/min	Units
Plastic J-Leaded Chip Carrier	44	15	45	35	°C/W
	68	13	38	29	°C/W
	84	12	37	28	°C/W
Plastic Quad Flatpack	100	13	48	40	°C/W
Very Thin (1.0 mm) Quad Flatpack	80	12	43	35	°C/W
Ceramic Pin Grid Array	84	8	33	20	°C/W
Ceramic Quad Flatpack	84	5	40	30	°C/W

General Power Equation

$$P = [I_{CC\text{standby}} + I_{CC\text{active}}] * V_{CC} + I_{OL} * V_{OL} * N + I_{OH} * (V_{CC} - V_{OH}) * M$$

Where:

$I_{CC\text{standby}}$ is the current flowing when no inputs or outputs are changing.

$I_{CC\text{active}}$ is the current flowing due to CMOS switching.

I_{OL} , I_{OH} are TTL sink/source currents.

V_{OL} , V_{OH} are TTL level output voltages.

N equals the number of outputs driving TTL loads to V_{OL} .

M equals the number of outputs driving TTL loads to V_{OH} .

An accurate determination of N and M is problematical because their values depend on the family type, design details, and on the system I/O. The power can be divided into two components: static and active.

Static Power Component

Actel FPGAs have small static power components that result in lower power dissipation than PALs or PLDs. By integrating multiple PALs/PLDs into one FPGA, an even greater reduction in board-level power dissipation can be achieved.

The power due to standby current is typically a small component of the overall power. Standby power is calculated below for commercial, worst case conditions.

I_{CC}	V_{CC}	Power
3 mA	5.25 V	15.75 mW (max)
1 mA	5.25 V	5.25 mW (typ)
0.75 mA	3.60 V	2.70 mW (max)
0.30 mA	3.30 V	0.99 mW (typ)

Active Power Component

Power dissipation in CMOS devices is usually dominated by the active (dynamic) power dissipation. This component is frequency dependent, a function of the logic and the external I/O. Active power dissipation results from charging internal chip capacitances of the interconnect, unprogrammed antifuses, module inputs, and module outputs, plus external capacitance due to PC board traces and load device inputs. An additional component of the active power dissipation is the totem-pole current in CMOS transistor pairs. The net effect can be associated with an equivalent capacitance that can be combined with frequency and voltage to represent active power dissipation.

Functional Timing Tests

AC timing for logic module internal delays is determined after place and route. The DirectTime Analyzer utility displays actual timing parameters for circuit delays. ACT 1 devices are AC tested to a “binning” circuit specification.

The circuit consists of one input buffer + n logic modules + one output buffer (n = 16 for A1010B; n = 28 for A1020B). The

logic modules are distributed along two sides of the device, as inverting or non-inverting buffers. The modules are connected through programmed antifuses with typical capacitive loading.

Propagation delay [$t_{PD} = (t_{PLH} + t_{PHL})/2$] is tested to the following AC test specifications.

Output Buffer Performance Derating (5V)



Note: The above curves are based on characterizations of sample devices and are not completely tested on all devices.

Output Buffer Performance Derating (3.3V)



Note: The above curves are based on characterizations of sample devices and are not completely tested on all devices.

ACT 1 Timing Module*



* Values shown for ACT 1 '-3 speed' devices at worst-case commercial conditions.

Predictable Performance: Tight Delay Distributions

Propagation delay between logic modules depends on the resistive and capacitive loading of the routing tracks, the interconnect elements, and the module inputs being driven. Propagation delay increases as the length of routing tracks, the number of interconnect elements, or the number of inputs increases.

From a design perspective, the propagation delay can be statistically correlated or modeled by the fanout (number of loads) driven by a module. Higher fanout usually requires some paths to have longer routing tracks.

The ACT 1 family delivers a very tight fanout delay distribution. This tight distribution is achieved in two ways: by decreasing the delay of the interconnect elements and by decreasing the number of interconnect elements per path.

Actel's patented PLICE antifuse offers a very low resistive/capacitive interconnect. The ACT 1 family's antifuses, fabricated in 1.0 micron lithography, offer nominal levels of 200 ohms resistance and 7.5 femtofarad (fF) capacitance per antifuse.

The ACT 1 fanout distribution is also tight due to the low number of antifuses required for each interconnect path. The ACT 1 family's proprietary architecture limits the number of antifuses per path to a maximum of four, with 90% of interconnects using two antifuses.

Timing Characteristics

Timing characteristics for ACT 1 devices fall into three categories: family dependent, device dependent, and design dependent. The input and output buffer characteristics are common to all ACT 1 family members. Internal routing delays are device dependent. Design dependency means actual delays are not determined until after placement and routing of the user design is complete. Delay values may then be determined by using the DirectTime Analyzer utility or performing simulation with post-layout delays.

Critical Nets and Typical Nets

Propagation delays are expressed only for typical nets, which are used for initial design performance evaluation. Critical net delays can then be applied to the most time-critical paths. Critical nets are determined by net property assignment prior to placement and routing. Up to 6% of the nets in a design may be designated as critical, while 90% of the nets in a design are typical.

Long Tracks

Some nets in the design use long tracks. Long tracks are special routing resources that span multiple rows, columns, or modules. Long tracks employ three and sometimes four antifuse connections. This increases capacitance and resistance, resulting in longer net delays for macros connected to long tracks. Typically, up to 6% of nets in a fully utilized device require long tracks. Long tracks contribute approximately 5 ns to 10 ns delay. This additional delay is represented statistically in higher fanout ($FO=8$) routing delays in the data sheet specifications section.

Timing Derating

A best case timing derating factor of 0.45 is used to reflect best case processing. Note that this factor is relative to the

“standard speed” timing parameters, and must be multiplied by the appropriate voltage and temperature derating factors for a given application.

Timing Derating Factor (Temperature and Voltage)

	Industrial		Military	
	Min.	Max.	Min.	Max.
(Commercial Minimum/Maximum Specification) x	0.69	1.11	0.67	1.23

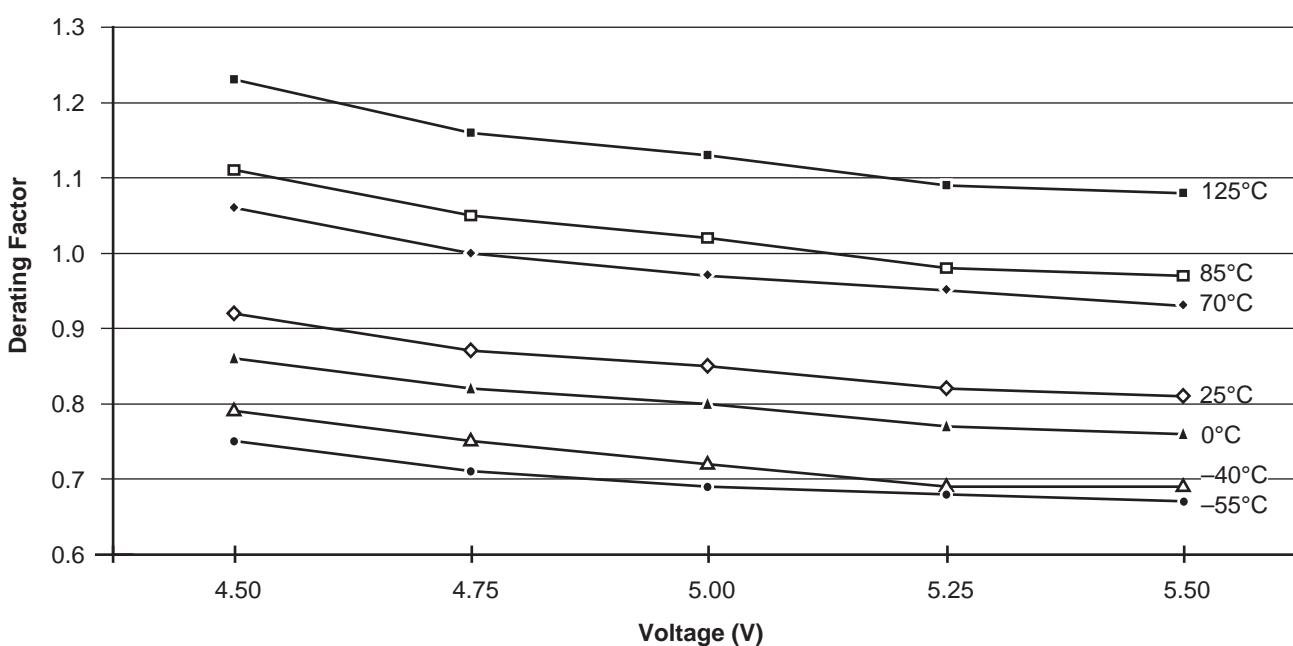
Timing Derating Factor for Designs at Typical Temperature ($T_J = 25^\circ\text{C}$) and Voltage (5.0 V)

(Commercial Maximum Specification) x	0.85
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Temperature and Voltage Derating Factors
(normalized to Worst-Case Commercial, $T_J = 4.75\text{ V}, 70^\circ\text{C}$)

	-55	-40	0	25	70	85	125
4.50	0.75	0.79	0.86	0.92	1.06	1.11	1.23
4.75	0.71	0.75	0.82	0.87	1.00	1.05	1.16
5.00	0.69	0.72	0.80	0.85	0.97	1.02	1.13
5.25	0.68	0.69	0.77	0.82	0.95	0.98	1.09
5.50	0.67	0.69	0.76	0.81	0.93	0.97	1.08

Junction Temperature and Voltage Derating Curves
(normalized to Worst-Case Commercial, $T_J = 4.75\text{ V}, 70^\circ\text{C}$)

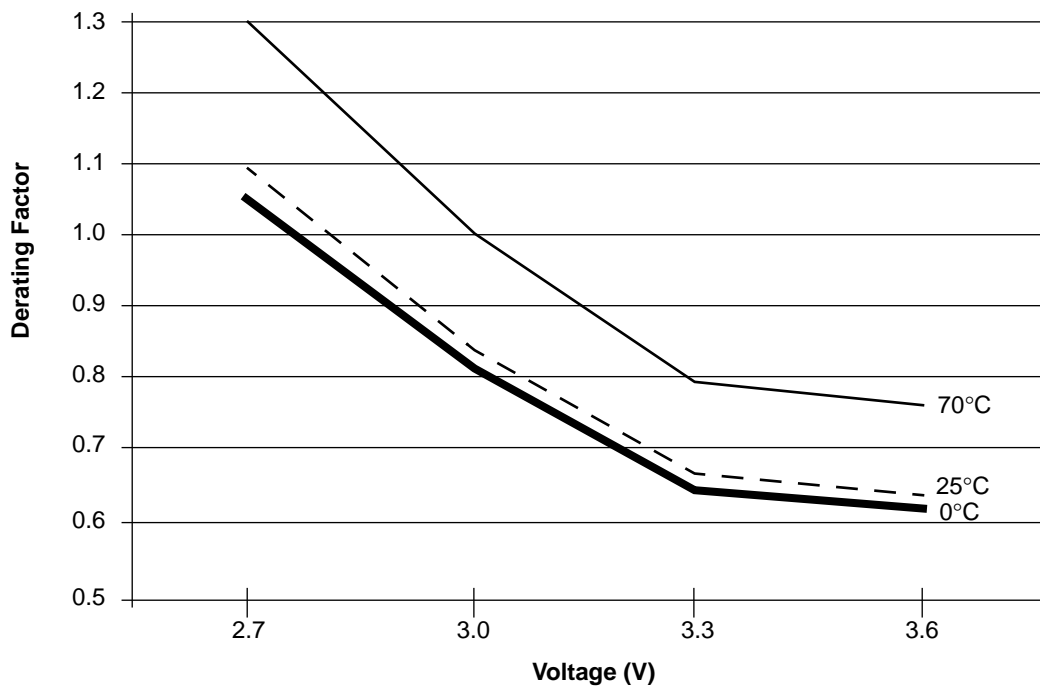


Note: This derating factor applies to all routing and propagation delays.

Temperature and Voltage Derating
Factors (normalized to Worst-Case
Commercial, $T_J = 3.0\text{ V}$, 70°C)

	0	25	70
2.7	1.05	1.09	1.30
3.0	0.81	0.84	1.00
3.3	0.64	0.67	0.79
3.6	0.62	0.64	0.76

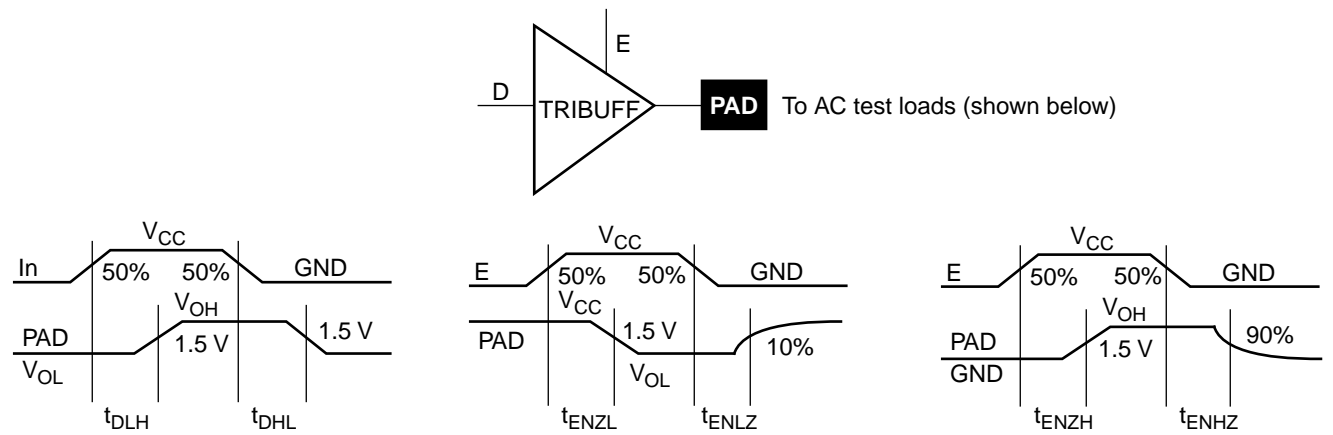
Junction Temperature and Voltage Derating Curves
(normalized to Worst-Case Commercial, $T_J = 3.0\text{ V}$, 70°C)



Note: This derating factor applies to all routing and propagation delays.

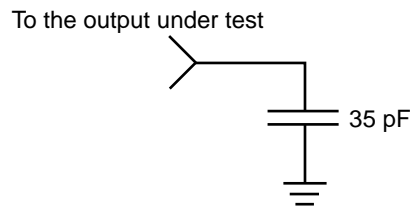
Parameter Measurement

Output Buffer Delays

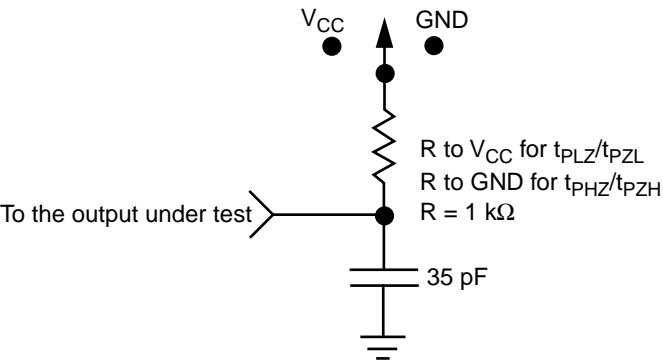


AC Test Loads

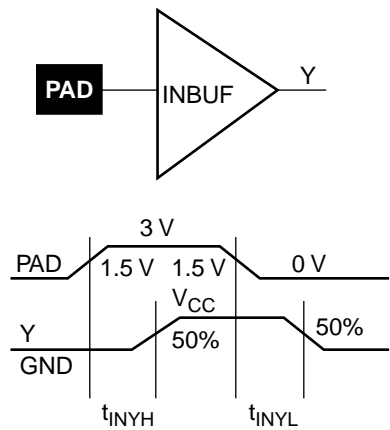
Load 1
(Used to measure propagation delay)



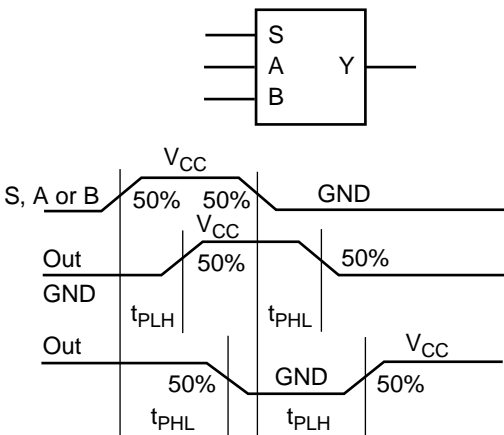
Load 2
(Used to measure rising/falling edges)



Input Buffer Delays

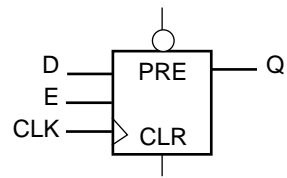


Module Delays

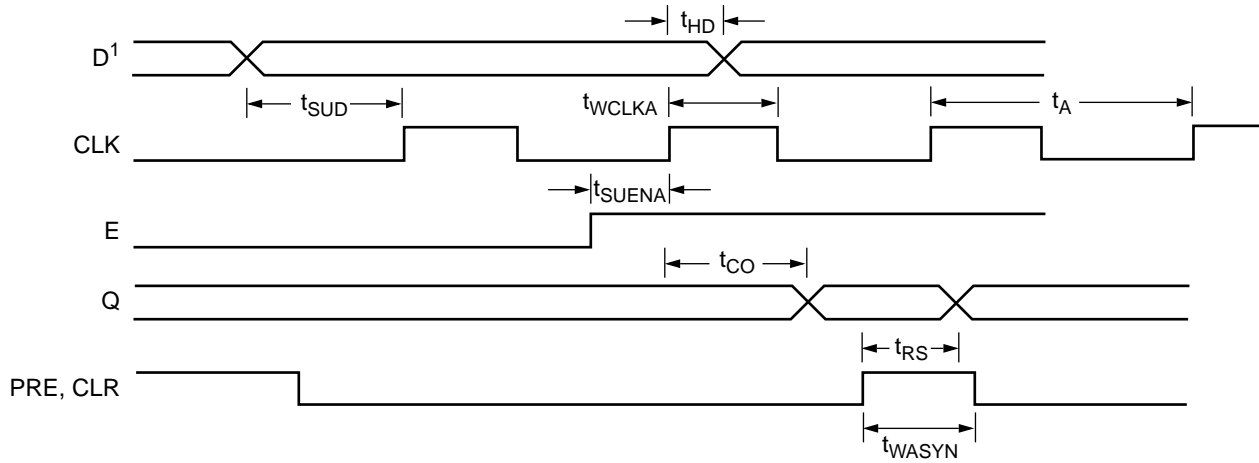


Sequential Timing Characteristics

Flip-Flops and Latches



(Positive edge triggered)



Note: *D represents all data functions involving A, B, S for multiplexed flip-flops.*

ACT 1 Timing Characteristics (continued)

(Worst-Case Commercial Conditions)

Output Module Timing		‘–3’ Speed		‘–2’ Speed		‘–1’ Speed		‘Std’ Speed		3.3 V Speed		
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
TTL Output Module Timing¹												
t _{DLH}	Data to Pad High	6.7	7.6	8.7	10.3	15.0	ns					
t _{DHL}	Data to Pad Low	7.5	8.6	9.8	11.5	16.7	ns					
t _{ENZH}	Enable Pad Z to High	6.6	7.5	8.6	10.2	14.8	ns					
t _{ENZL}	Enable Pad Z to Low	7.9	9.1	10.4	12.2	17.7	ns					
t _{ENHZ}	Enable Pad High to Z	10.0	11.6	13.1	15.4	22.4	ns					
t _{ENLZ}	Enable Pad Low to Z	9.0	10.4	11.8	13.9	20.2	ns					
d _{TLH}	Delta Low to High	0.06	0.07	0.08	0.09	0.13	ns/pF					
d _{THL}	Delta High to Low	0.08	0.09	0.10	0.12	0.17	ns/pF					
CMOS Output Module Timing¹												
t _{DLH}	Data to Pad High	7.9	9.2	10.4	12.2	17.7	ns					
t _{DHL}	Data to Pad Low	6.4	7.2	8.2	9.8	14.2	ns					
t _{ENZH}	Enable Pad Z to High	6.0	6.9	7.9	9.2	13.4	ns					
t _{ENZL}	Enable Pad Z to Low	8.3	9.4	10.7	12.7	18.5	ns					
t _{ENHZ}	Enable Pad High to Z	10.0	11.6	13.1	15.4	22.4	ns					
t _{ENLZ}	Enable Pad Low to Z	9.0	10.4	11.8	13.9	20.2	ns					
d _{TLH}	Delta Low to High	0.10	0.11	0.13	0.15	0.22	ns/pF					
d _{THL}	Delta High to Low	0.06	0.07	0.08	0.09	0.13	ns/pF					

Notes:

1. Delays based on 35 pF loading.
2. SSO information can be found in the “Simultaneous Switching Output Limits for Actel FPGAs” application note on page 4-125.

Package Pin Assignments

44-Pin PLCC



68-Pin PLCC



Signal	A1010B Function	A1020B Function
3	VCC	VCC
10	GND	GND
14	VCC	VCC
16	VCC	VCC
21	GND	GND
25	VCC	VCC
32	GND	GND
33	CLK, I/O	CLK, I/O
34	MODE	MODE
35	VCC	VCC
36	SDI, I/O	SDI, I/O
37	DCLK, I/O	DCLK, I/O
38	PRA, I/O	PRA, I/O
39	PRB, I/O	PRB, I/O
43	GND	GND

Signal	A1010B, A10V10B Function	A1020B, A10V20B Functions
4	VCC	VCC
14	GND	GND
15	GND	GND
21	VCC	VCC
25	VCC	VCC
32	GND	GND
38	VCC	VCC
49	GND	GND
52	CLK, I/O	CLK, I/O
54	MODE	MODE
55	VCC	VCC
56	SDI, I/O	SDI, I/O
57	DCLK, I/O	DCLK, I/O
58	PRA, I/O	PRA, I/O
59	PRB, I/O	PRB, I/O
66	GND	GND

Notes:

1. NC: Denotes No Connection
2. All unlisted pin numbers are user I/Os.
3. MODE should be terminated to GND through a 10K resistor to enable Actionprobe usage; otherwise it can be terminated directly to GND.

Package Pin Assignments (continued)

84-Pin PLCC



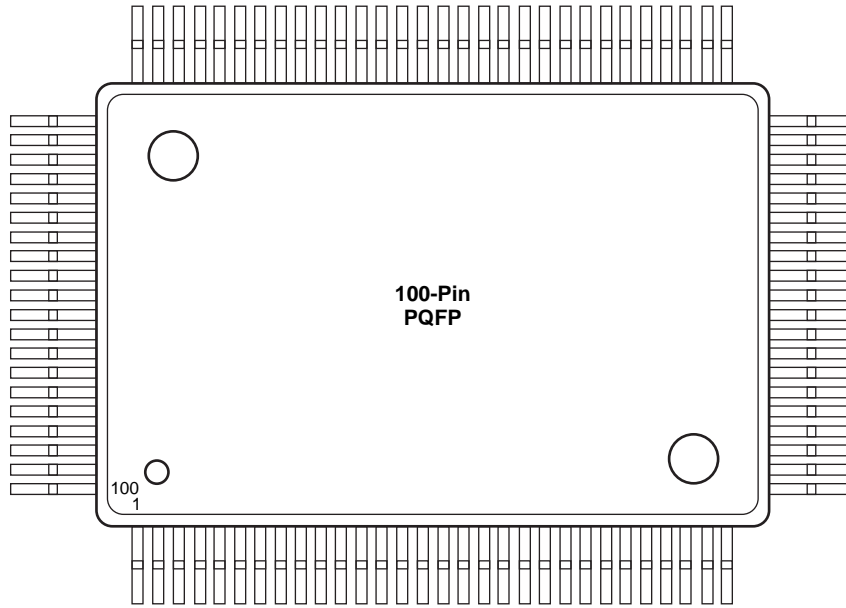
Signal	A1020B, A10V20B Function
4	VCC
12	NC
18	GND
19	GND
25	VCC
26	VCC
33	VCC
40	GND
46	VCC
60	GND
61	GND
64	CLK, I/O
66	MODE
67	VCC
68	VCC
72	SDI, I/O
73	DCLK, I/O
74	PRA, I/O
75	PRB, I/O
82	GND

Notes:

1. NC: Denotes No Connection
2. All unlisted pin numbers are user I/Os.
3. MODE should be terminated to GND through a 10K resistor to enable Actionprobe usage; otherwise it can be terminated directly to GND.

Package Pin Assignments (continued)

100-Pin PQFP



Pin	A1010B Function	A1020B Function
1	NC	NC
2	NC	NC
3	NC	NC
4	NC	NC
5	NC	NC
6	PRB, I/O	PRB, I/O
13	GND	GND
19	VCC	VCC
27	NC	NC
28	NC	NC
29	NC	NC
30	NC	NC
31	NC	I/O
32	NC	I/O
33	NC	I/O
36	GND	GND
37	GND	GND
43	VCC	VCC
44	VCC	VCC
48	NC	I/O
49	NC	I/O
50	NC	I/O
51	NC	NC
52	NC	NC

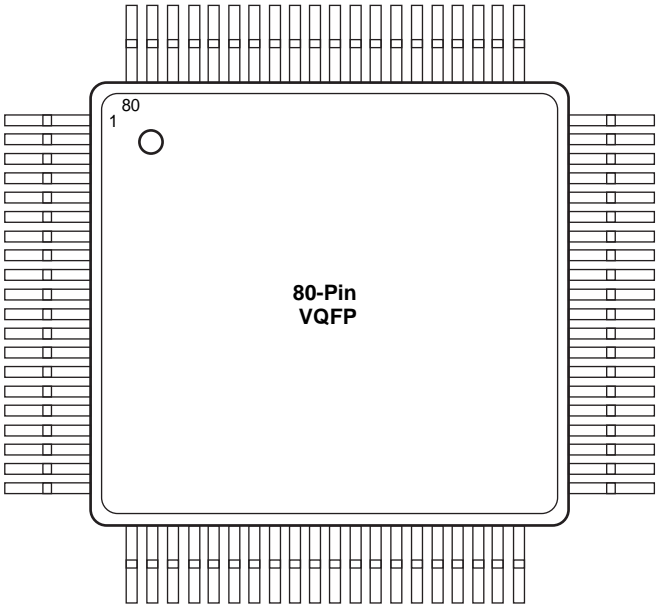
Pin	A1010B Function	A1020B Function
53	NC	NC
54	NC	NC
55	NC	NC
56	VCC	VCC
63	GND	GND
69	VCC	VCC
77	NC	NC
78	NC	NC
79	NC	NC
80	NC	I/O
81	NC	I/O
82	NC	I/O
86	GND	GND
87	GND	GND
90	CLK, I/O	CLK, I/O
92	MODE	MODE
93	VCC	VCC
94	VCC	VCC
95	NC	I/O
96	NC	I/O
97	NC	I/O
98	SDI, I/O	SDI, I/O
99	DCLK, I/O	DCLK, I/O
100	PRA, I/O	PRA, I/O

Notes:

1. NC: Denotes No Connection
2. All unlisted pin numbers are user I/Os.
3. MODE should be terminated to GND through a 10K resistor to enable Actionprobe usage; otherwise it can be terminated directly to GND.

Package Pin Assignments (continued)

80-Pin VQFP



Pin	A1010B, A10V10B Function	A1020B, A10V20B Function
2	NC	I/O
3	NC	I/O
4	NC	I/O
7	GND	GND
13	VCC	VCC
17	NC	I/O
18	NC	I/O
19	NC	I/O
20	VCC	VCC
27	GND	GND
33	VCC	VCC
41	NC	I/O
42	NC	I/O
43	NC	I/O

Pin	A1010B, A10V10B Function	A1020B, A10V20B Function
47	GND	GND
50	CLK, I/O	CLK, I/O
52	MODE	MODE
53	VCC	VCC
54	NC	I/O
55	NC	I/O
56	NC	I/O
57	SDI, I/O	SDI, I/O
58	DCLK, I/O	DCLK, I/O
59	PRA, I/O	PRA, I/O
60	NC	NC
61	PRB, I/O	PRB, I/O
68	GND	GND
74	VCC	VCC

Notes:

- 1. NC: Denotes No Connection
- 2. All unlisted pin numbers are user I/Os.
- 3. MODE should be terminated to GND through a 10K resistor to enable Actionprobe usage; otherwise it can be terminated directly to GND.

Package Pin Assignments (continued)

84-Pin CPGA



Pin	A1010B Function	A1020B Function
A11	PRA, I/O	PRA, I/O
B1	NC	I/O
B2	NC	NC
B5	VCC	VCC
B7	GND	GND
B10	PRB, I/O	PRB, I/O
B11	SDI, I/O	SDI, I/O
C1	NC	I/O
C2	NC	I/O
C10	DCLK, I/O	DCLK, I/O
C11	NC	I/O
D10	NC	I/O
D11	NC	I/O
E2	GND	GND
E3	GND	GND
E9	VCC	VCC

Pin	A1010B Function	A1020B Function
E10	VCC	VCC
E11	MODE	MODE
F1	VCC	VCC
F9	CLK, I/O	CLK, I/O
F10	GND	GND
G2	VCC	VCC
G10	GND	GND
J2	NC	I/O
J10	NC	I/O
K1	NC	I/O
K2	VCC	VCC
K5	GND	GND
K7	VCC	VCC
K10	NC	I/O
K11	NC	I/O
L1	NC	I/O

Notes:

1. NC: Denotes No Connection
2. All unlisted pin numbers are user I/Os.
3. MODE should be terminated to GND through a 10K resistor to enable Actionprobe usage; otherwise it can be terminated directly to GND.

Package Pin Assignments (continued)

84-Pin CQFP



Pin	A1020B Function
1	NC
7	GND
8	GND
14	VCC
15	VCC
22	VCC
29	GND
35	VCC
49	GND
50	GND

Pin	A1020B Function
53	CLK, I/O
55	MODE
56	VCC
57	VCC
61	SDI, I/O
62	DCLK, I/O
63	PRA, I/O
64	PRB, I/O
71	GND
77	VCC

- Notes:**
- 1. NC: Denotes No Connection
 - 2. All unlisted pin numbers are user I/Os.
 - 3. MODE should be terminated to GND through a 10K resistor to enable Actionprobe usage; otherwise it can be terminated directly to GND.

